

COMPOUND FIELD EFFECT POWER TRANSISTOR
 μ PA1640

MONOLITHIC POWER MOS FET ARRAY

DESCRIPTION

The μ PA1640 is Monolithic N-channel Power MOS FET Array that built in 8 circuits with 2 AND GATE.

In groups of 4 circuits and they each have ENABLE terminal.

FEATURES

- Wired Connection is possible. (Output Step is Open Drain)
- Output Voltage: $V_o = 30$ V MAX.
Output Current: $I_o = 100$ mA MAX.
- Wide Operation Temperature: -40 to $+85$ °C

ORDERING INFORMATION

Part Number	Package	Quality Grade
μ PA1640GS	20-Pin SOP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25$ °C)

Supply Voltage	V_{DD}	-0.5 to $+7.0$	V
Output Voltage	V_o	-0.5 to $+30$	V
Input Voltage	V_i	-0.5 to $V_{DD} + 0.5$	V
Output Current	I_o	± 100	mA
Input Current	I_i	-10 to $+0.1$	mA/unit
Total Power Dissipation	P_d	1.0	W/PKG
Operating Temperature	T_{opt}	-40 to $+85$	°C
Storage Temperature	T_{stg}	-55 to $+150$	°C

TRUTH TABLE

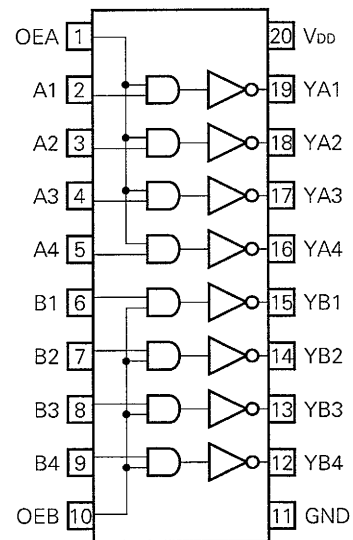
INPUT		OUTPUT	INPUT		OUTPUT
OUTPUT ENABLE A	A	YA	OUTPUT ENABLE B	B	YB
H	L	Z	H	L	Z
H	H	L	H	H	L
L	X	Z	L	X	Z

H: High-Level

L: Low-Level

Z: High-Impedance

CONNECTION DIAGRAM



RECOMMENDED OPERATING CONDITIONS (T_a = -40 to +85 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{DD}	4.5	5.0	5.5	V
Output Voltage	V _O			24	V
Input Voltage	V _I	0		V _{DD}	V
Low-Level Input Voltage	V _{IL}	0		0.3 V _{DD}	V
High-Level Input Voltage	V _{IH}	0.7 V _{DD}		V _{DD}	V
Low-Level Output Current	I _{OL}		48		mA
Operation Temperature	T _{opt}	-10		60	°C

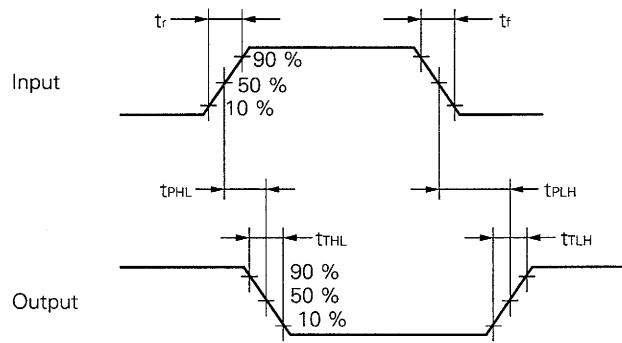
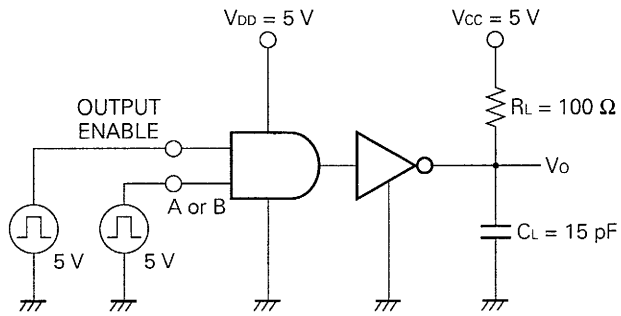
ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Low Level Output Voltage	V _{OL1}			0.2	V	V _{DD} = 4.5 V, V _I = 2 V, I _O = 24 mA
	V _{OL2}			0.4	V	V _{DD} = 4.5 V, V _I = 2 V, I _O = 48 mA
	V _{OL3}			0.8	V	V _{DD} = 4.5 V, V _I = 2 V, I _O = 100 mA
Output Leakage Current	I _{TL}			5	μA	V _{DD} = 5.5 V, V _O = 30 V, V _I = 0
Low-Level Input Voltage	V _{IL}			1.5	V	V _{DD} = 5 V, V _O = 30 V, I _O ≤ 20 μA
High-Level Input Voltage	V _{IH}	3.5			V	V _{DD} = 5 V, V _O = 0.4 V, I _O ≥ 48 mA
Input Current	I _I			±1	μA	V _{DD} = 5.5 V, V _I = 0 or V _{DD}
Quiescent Supply Current	I _{DD}			10	μA	V _{DD} = 5.5 V, V _I = 0 or V _{DD} , I _O = 0
Input Capacitance	C _I		7	15	pF	
Body Equivalent Capacitance	C _{pd}		30		pF	

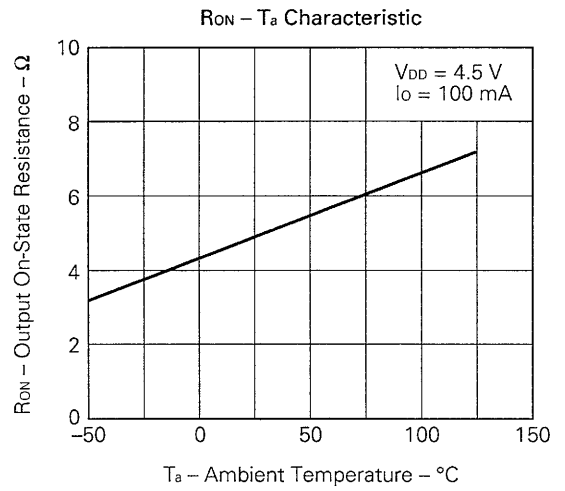
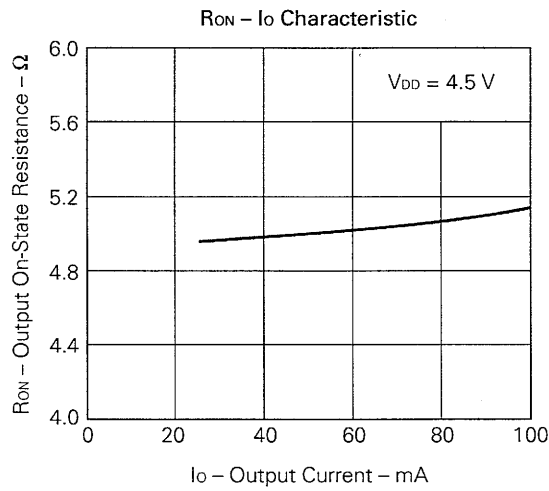
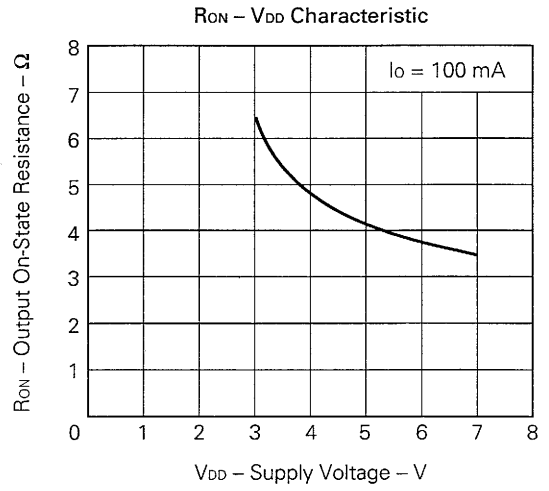
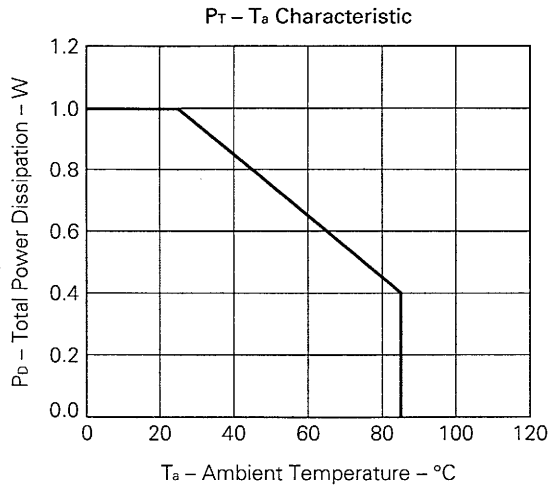
ELECTRICAL CHARACTERISTICS (T_a = 25 °C, V_{DD} = V_{CC} = 5 V, C_L = 15 pF, R_L = 100 Ω, t_r = t_f = 5 ns)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Delay Time	t _{pZL} t _{pLZ}		20	30	ns	A,B → Y, OEA, OEB=H
	t _{pZL} t _{pLZ}		20	30	ns	OUTPUT ENABLE → Y, A,B = H
Rise Time	t _{TLH}		20	30	ns	
Fall Time	t _{THL}		20	30	ns	

SWITCHING WAVE FORMS AND TEST CIRCUITS

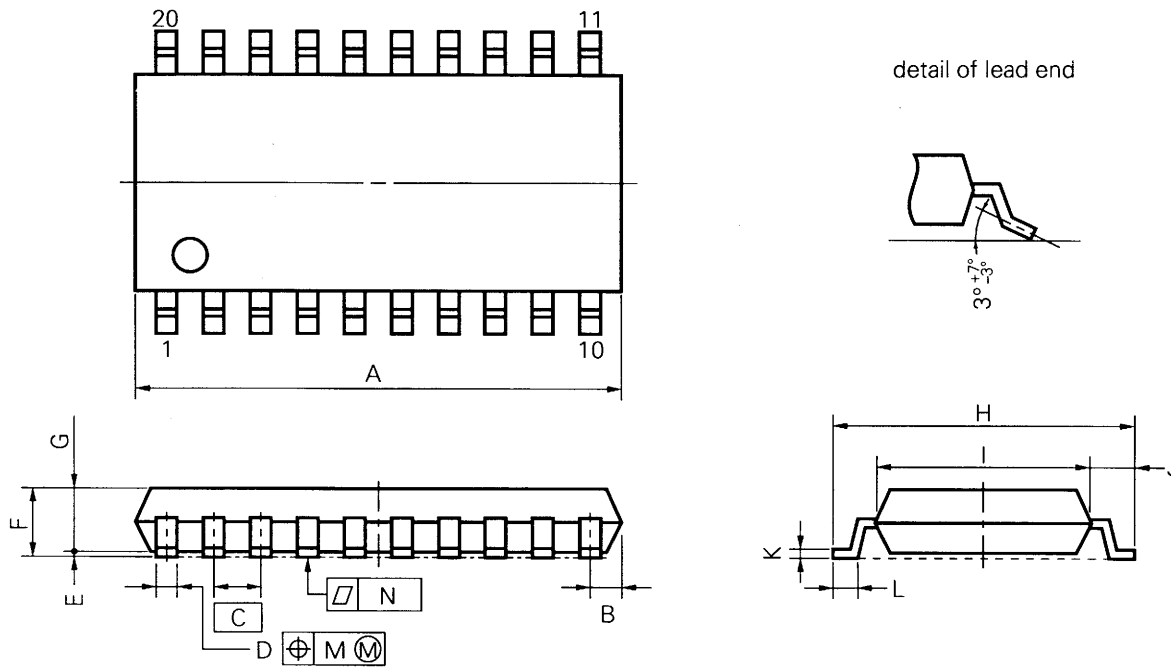


TYPICAL CHARACTERISTICS ($T_a = 25\text{ }^\circ\text{C}$)



PACKAGE DIMENSIONS

20 PIN PLASTIC SOP (300 mil)



NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

P20GM-50-300B,C-3

ITEM	MILLIMETERS	INCHES
A	13.00 MAX.	0.512 MAX.
B	0.78 MAX.	0.031 MAX.
C	1.27 (T.P.)	0.050 (T.P.)
D	0.40 ^{+0.10} _{-0.05}	0.016 ^{+0.004} _{-0.003}
E	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
H	7.7±0.3	0.303±0.012
I	5.6	0.220
J	1.1	0.043
K	0.20 ^{+0.10} _{-0.05}	0.008 ^{+0.004} _{-0.002}
L	0.6±0.2	0.024 ^{+0.008} _{-0.009}
M	0.12	0.005
N	0.10	0.004

RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SEMICONDUCTOR DEVICES TECHNOLOGY MANUAL" (IEI-1207).
μPA1640GS

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 235 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 2 or below, Exposure limit*: None	IR35-00-2
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 2 or below, Exposure limit*: None	VP15-00-2
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below, Number of flow process: 1, Exposure limit*: None	WS60-00-1

*: Exposure limit before soldering after dry-pack package is opened.
Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method".

Reference

Document name	Document No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Semiconductor device package manual	IEI-1213
SMD surface mount technology manual	IEI-1207

[MEMO]

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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.